# Si Time

# Automotive Temperature Range Oscillator

### **Features**

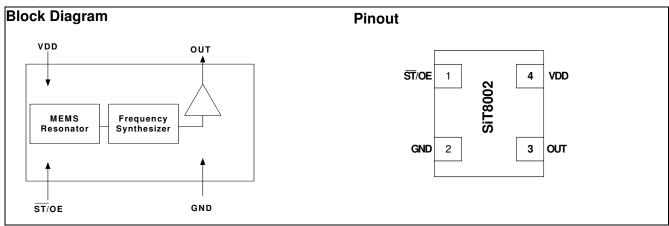
- · Operating temperature range:
  - Automotive, -40 °C to +125 °C
- · Mechanically robust:
  - · Shock, 50 KG
  - · Vibration, 70 G
- · Wide frequency range
  - 1 MHz to 125 MHz
- · Low frequency tolerance
  - ±100 ppm or ±200 ppm or ±500
- · Operating voltage
  - 1.8V or 2.5 or 3.3 V
- · Small footprint
  - 2.5 x 2.0 x 0.85 mm
  - 3.2 x 2.5 x 0.85 mm
  - 5.0 x 3.2 x 0.85 mm
  - 7.0 x 5.0 x 0.85 mm
- All packages are Pb-free and ROHs compliant (QFN SMD)
- Ultra-reliable start up and greater immunity from interference
- High drive option: 30pF load (contact factory)

### **Benefits**

- · No crystal or capacitors required
- · Eliminates crystal qualification time
- 50% + board saving space
- Most cost effective than Quartz oscillators, Quartz crystals and Clock ICs.
- · completely quartz-free

### **Applications**

- Automotive
- · Industrial
- Automation
- Space
- Satellite



# Pin Description

Pin No.	Name	Pin Description
1	ST/OE	Standby/ Output Enable
2	GND	Connect to Ground
3	OUT	1 to 125 MHz Programmed Clock output
4	VDD	Connect to 1.8V or 2.5V or 3.3V

### Pin1

Pin #1 Functionality
OE
H or Open; specified frequency output
L: output is high impedance
ST
H or Open; specified frequency output
L: output is low level (weak pull down) oscillation stops

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### Description

The SiT8002AA oscillator family is composed of the world's smallest, high-performance programmable oscillators. The SiT8002AA is suitable for use in clock generation for automotive, industrial, and space/Satellite applications.

MEMS resonators are 1000x smaller by volume than quartz resonators and are built in high volume CMOS fabs instead of small custom manufacturing facilities. Due to their small size, massive lot sizes, and simpler manufacturing processes MEMS oscillators are inherently more reliable, have more consistent performance and are always in stock.

The SiT8002AA, by eliminating the quartz crystals, has improved immunity to the environmental effects of vibration, shock, strain, and humidity.

### **Absolute Maximum Ratings**

Attempted operation outside the absolute maximum ratings of the part may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications not absolute maximum ratings.

### **Absolute Maximum Table**

Parameter	Min.	Max.	Unit
Storage Temperature	-65	150	.€
VDD	-0.5	+3.65	V
Electrostatic Discharge		6000	V
Theta JA ( with copper plane on VDD and GND)	_	75	°C/W
Theta JC (with PCB traces of 0.010 inch to all pins)	_	24	°C/W
Soldering Temperature (follow standard Pb free soldering guidelines)		260	.€
Number of Program Writes		1	NA
Program Retention over -40 to 125C, Process, VDD (0 to 3.6V)		1,000+	years

### **Operating Conditions**

Parameter	Min.	Тур.	Max.	Unit
Supply Voltages, VDD <sup>[1]</sup>	2.97	3.3	3.63	V
	2.25	2.5	2.75	V
	1.7	1.8	1.9	V
Automotive OperatingTemperature	-40	-	125	.€
Maximum Load Capacitance <sup>[2]</sup>	-	-	15	pF
VDD Ramp Time	0	-	200	ms

### **Environmental Compliance**

Parameter	Condition/Test Method
Mechanical Shock	MIL-STD-883F, Method 2002, 50 KG
Mechanical Vibration	MIL-STD-883F, Method 2007, 70 G
Temperature Cycle	JESD22, Method A104
Solderability	MIL-STD-883F, Method 2003
Moisture Sensibility Level	MSL1

#### Notes

- 1. The 2.5V device can operate from 2.25V to 3.63V with higher output drive, however, the data sheet parameters cannot be guaranteed. Please contact factory for this option.
- 2. The output driver strenght can be programmed to drive up to 30pF load. Please contact factory for this option.

# SiT8002AA



# **DC Electrical Specifications**

# @VDD = 3.3V ±10%, -40 to 125℃

Parameter	Condition	Min.	Тур.	Max.	Unit
Voltage Output High	IOH = -20 mA	70	-	-	%Vdd
Voltage Output Low	IOL = 20 mA	-	-	30	%Vdd
Input Voltage High	Pin 1	70	-	-	%Vdd
Input Voltage Low	Pin 1	-	-	30	%Vdd
Operating Current	Output frequency = 65 MHz, 15 pF load	-	-	30	mA
Standby Current	Output is weakly pulled down, ST = GND	-	30	80	uA
Power Up Time	Time from minimum power supply voltage	-	12	50	ms

### @VDD = 2.5V ±10%, -40 to 125℃

Parameter	Condition	Min.	Тур.	Max.	Unit
Voltage Output High	IOH = -15 mA	70	-	-	%Vdd
Voltage Output Low	IOL = 15 mA	-	-	30	%Vdd
Input Voltage High	Pin 1	70	-	-	%Vdd
Input Voltage Low	Pin 1	-	-	30	%Vdd
Operating Current	Output frequency = 65 MHz, 15 pF load	-	-	30	mA
Standby Current	Output is weakly pulled down, ST = GND	-	30	80	uA
Power Up Time	Time from minimum power supply voltage	-	12	50	ms

# @VDD = 1.8V $\pm$ 5%, -40 to 125℃

Parameter	Condition	Min.	Тур.	Max.	Unit
Voltage Output High	IOH = -10 mA	70	-	-	%Vdd
Voltage Output Low	IOL = 10 mA	-	-	30	%Vdd
Input Voltage High	Pin 1	70	-	-	%Vdd
Input Voltage Low	Pin 1	-	-	30	%Vdd
Operating Current	Output frequency = 65 MHz, 15 pF load	-	-	25	mA
Standby Current	Output is weakly pulled down, ST = GND	-	30	80	uA
Power Up Time	Time from minimum power supply voltage	-	12	50	ms

# SiT8002AA



# **AC Electrical Specifications**

@VDD =  $3.3V \pm 10\%$ , -40 to 125%

Parameter	Condition	Min.	Тур.	Max.	Unit
Clock Output Frequency		1	-	125	MHz
Frequency Tolerance	Initial tolerance, operating temperature, rated	-100	-	+100	ppm
	power supply voltage change, load change, aging, shock and vibration	-200	-	+200	ppm
		-500	-	+500	ppm
Clock Output Duty Cycle	Output frequency= 1 MHz to 125 MHz	45	-	55	%
Clock Output Rise Time	15 pF Load, 20% to 80% VDD	-	1.0	3	ns
Clock Output Fall Time	15 pF Load, 80% to 20% VDD	-	1.0	3	ns
Pk-pk Period Jitter	Output frequency = 24 MHz	-	100	125	ps
	Output frequency = 100 MHz	-	60	75	ps

# @VDD = $2.5V \pm 10\%$ , -40 to 125 °C

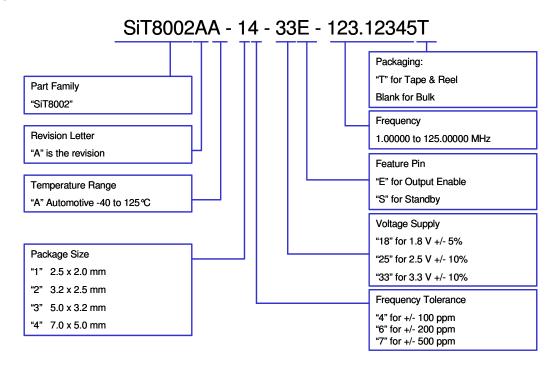
Parameter	Condition	Min.	Тур.	Max.	Unit
Clock Output Frequency		1	-	125	MHz
Frequency Tolerance	Initial tolerance, operating temperature, rated power supply voltage change, load change,aging, shock and vibration	-100	-	+100	ppm
		-200	-	+200	ppm
		-500	-	+500	ppm
Clock Output Duty Cycle	Output frequency= 1MHz to 125MHz	45	-	55	%
Clock Output Rise Time	15 pF Load, 20% to 80% VDD	-	1.0	3	ns
Clock Output Fall Time	15 pF Load, 80% to 20% VDD	-	1.0	3	ns
Pk-pk Period Jitter	Output frequency = 24 MHz	-	130	150	ps
	Output frequency = 100 MHz	-	60	75	ps

# @VDD = 1.8V ±5%, -40 to 125℃

Parameter	Condition	Min.	Тур.	Max.	Unit
Clock Output Frequency		1	-	125	MHz
Frequency Tolerance	Initial tolerance, operating temperature, rated	-50	-	+50	ppm
	power supply voltage change, load change, aging, shock and vibration	-100	-	+100	ppm
Clock Output Duty Cycle	Output frequency= 1 MHz to 65MHz	45	-	55	%
	Output frequency= 65 MHz to 125MHz	40	-	60	%
Clock Output Rise Time	15 pF Load, 20% to 80% VDD	-	1.0	3	ns
Clock Output Fall Time	15 pF Load, 80% to 20% VDD	-	1.0	3	ns
Pk-pk Period Jitter	Output frequency = 24 MHz	-	185	225	ps
	Output frequency = 100 MHz	-	100	125	ps



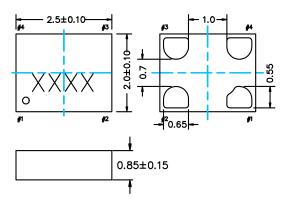
### **Ordering Information**



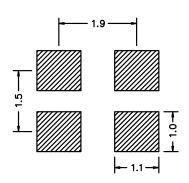
# Package Information [3]

Dimension (mm)

# 2.5 x 2.0 x 0.85mm



### Land Pattern (recommneded) (mm)



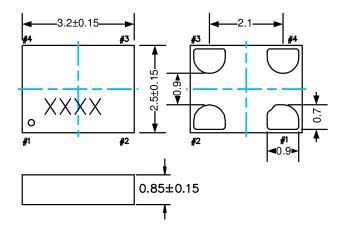


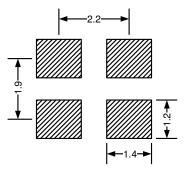
# Package Information (continued)[3]

Dimension (mm)

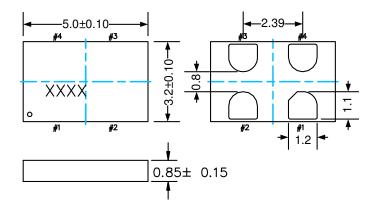
### Land Pattern (recommneded) (mm)

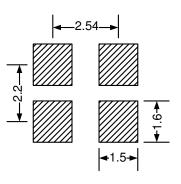
### 3.2 x 2.5 x 0.85mm



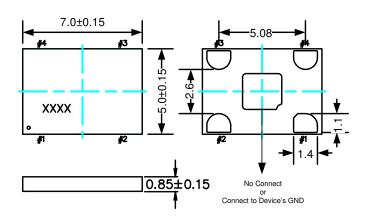


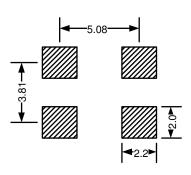
### 5.0 x 3.2 x 0.85mm





### 7.0 x 5.0 x 0.85mm





#### Note:

3. xxxx top marking denotes manufacturing lot number.





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